

EAST - [10 092887 - Amorphous SiC window coating.wsp.1]			
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1 1168	(amorphous adj silicon ADJ carbide) WITH (coating or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 14:35
2 1256	(257/76,77.ccls. 438/105,931.ccls. )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 14:56
3 2	(amorphous adj silicon ADJ carbide) and (electromagnetic adj interference)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 14:57
4 72	(257/76,77.ccls. 438/105,931.ccls. ) and (amorphous adj silicon ADJ carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 15:13
5 13	((257/76,77.ccls. 438/105,931.ccls. ) and (amorphous adj silicon ADJ carbide)) and (transparent with light)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 16:51
6 1	((257/76,77.ccls. 438/105,931.ccls. ) and (amorphous adj silicon ADJ carbide)) and (electromagnetic with interference)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 16:57
7 1	((257/76,77.ccls. 438/105,931.ccls. ) and (amorphous adj silicon ADJ carbide)) and (emi)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 16:56
8 2	(amorphous adj silicon ADJ carbide) and (emi)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/21 13:16
9 3	(amorphous adj silicon ADJ carbide) and (electromagnetic with interference)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 14:38
10 2	6031250.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 17:08
11 2	6268229.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 17:09
12 1	"09/557165"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 17:10
13 6	"557165"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/10 17:10
14 77	((electromagnetic adj interference) with shield) same film	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 13:58
15 13	((electromagnetic adj interference) with shield) same (thin adj film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 14:36
16 6	("5270488" "5153379" "5166772").pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 14:07
17 186	(amorphous adj silicon ADJ carbide) same (conductivity or resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/11 14:50
18 104	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/16 12:35

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18 104	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/16 12:35
19 9	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity) and omega	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/11 15:08
20 9	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity) and "omega"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/11 15:09
21 0	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity) and thickness and ".mu."	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/16 12:36
22 63	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity) and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/16 14:45
23 1	(amorphous adj silicon ADJ carbide) with (conductivity or resistivity) and thickness and glue	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/16 13:27
24 50	(amorphous adj silicon ADJ carbide) and ((glue or bonding or adhesive or bonded) adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 15:19
25 13	(amorphous adj silicon ADJ carbide) with sensor	USPAT	2002/10/16 14:56
26 6	(amorphous adj silicon ADJ carbide) with sensor and temperature	USPAT	2002/10/17 14:43
27 0	(amorphous adj silicon ADJ carbide) with sensor same temperature	USPAT	2002/10/16 14:56
28 2	(amorphous adj silicon ADJ carbide) with sensor and (high adj temperature)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 14:03
29 1	(amorphous adj silicon ADJ carbide) with sensor and (high adj temperature) and doped	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 14:04
30 1	(amorphous adj silicon ADJ carbide) same sensor same (high adj temperature) same doped	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 14:05
31 3	(amorphous adj silicon ADJ carbide) and sensor same (high adj temperature) same doped	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 14:06
32 1	(amorphous adj silicon ADJ carbide) with diffusion adj barrier	USPAT	2002/10/17 14:44
33 4	4109271.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 15:20
34 2	4451119.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/17 15:20
35 148	(amorphous adj silicon ADJ carbide) with (thin adj film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/10/21 13:17

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2	INZZ	silicon ADJ carbide AND Mehregany\$.AU.	unrestricted	44	<a href="#">show titles</a>
3	INZZ	high ADJ temperature SAME pressure ADJ sensor AND silicon ADJ carbide	unrestricted	11	<a href="#">show titles</a>
4	INZZ	3 AND cavity	unrestricted	1	<a href="#">show titles</a>

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